



Features

- Formerly **FulTec** brand
- Extremely high speed performance
- Low impedance
- Two TBU® protectors in one small package
- Very high bandwidth, GHz compatible
- Simple, superior circuit protection
- RoHS compliant*, UL Recognized 

Applications

- xDSL (ADSL, VDSL, VDSL2)
- High Data Rate Interface IC protection (LVDS, HDMI, etc.)
- Industrial sensors and controls
- General electronics

P40-G Series TBU® High-Speed Protectors

Transient Blocking Units - TBU® Devices

Bourns® Model P40-G products are high-speed bidirectional protection components, constructed using MOSFET semiconductor technology, designed to protect against faults caused by short circuits, AC power cross, induction and lightning surges.

The TBU® high-speed protector, triggering as a function of the MOSFET, blocks surges and provides an effective barrier behind which sensitive electronics are not exposed to large voltages or currents during surge events. The TBU® device is provided in a surface mount DFN package and meets industry standard requirements such as RoHS and Pb Free solder reflow profiles.

Agency Approval

UL recognized component File # E315805.

Industry Standards

Description		Model
Telcordia	GR-1089	P40-G
ITU-T	K.20, K.20E, K.21, K.21E, K.45	

Absolute Maximum Ratings (T_{amb} = 25 °C)

Symbol	Parameter	Value	Unit
V _{imp}	Maximum protection voltage for impulse faults with rise time $\geq 1 \mu\text{sec}$	40	V
V _{rms}	Maximum protection voltage for continuous V _{rms} faults	28	V
T _{op}	Operating temperature range	-55 to +125	°C
T _{stg}	Storage temperature range	-65 to +150	°C
T _{jmax}	Maximum Junction Temperature	+125	°C

Electrical Characteristics (T_{amb} = 25 °C)

Symbol	Parameter	Min.	Typ.	Max.	Unit
I _{op}	Maximum current through the device that will not cause current blocking			240	mA
I _{trigger}	Typical current for the device to go from normal operating state to protected state		350		mA
I _{out}	Maximum current through the device			480	mA
R _{device}	Series resistance of the TBU® device		3.6	4.2	Ω
R _{bal}	Line-to line series resistance difference between two TBU® devices			5	%
t _{block}	Maximum time for the device to go from normal operating state to protected state			0.2	μs
I _{quiescent}	Current through the triggered TBU® device with 40 Vdc circuit voltage		0.7		mA
V _{reset}	Voltage below which the triggered TBU® device will transition to normal operating state		7		V
R _{θJA}	Junction to air thermal resistance, FR4 PCB. 0.035 sq. in. of copper in addition to solder pads		130		°C/W

The P40-G Series TBU® high-speed protector is bidirectional; specifications are valid in both directions.

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.
Specifications are subject to change without notice.

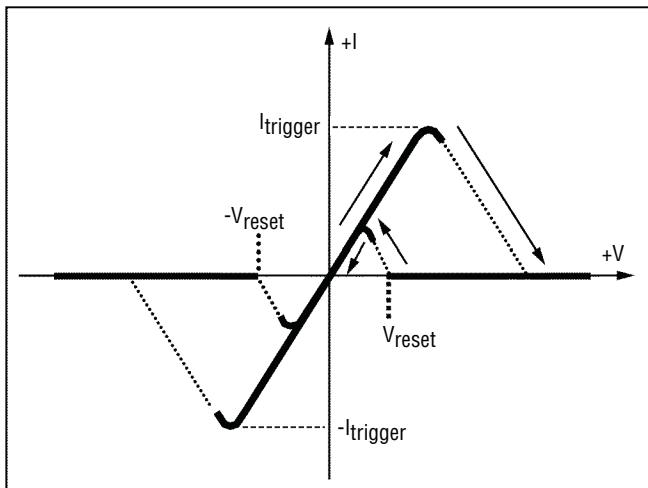
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
Users should verify actual device performance in their specific applications.

P40-G Series TBU® High-Speed Protectors

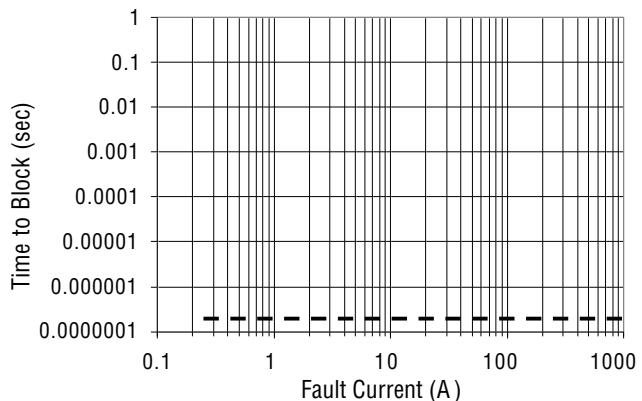
BOURNS®

Typical Performance Characteristics

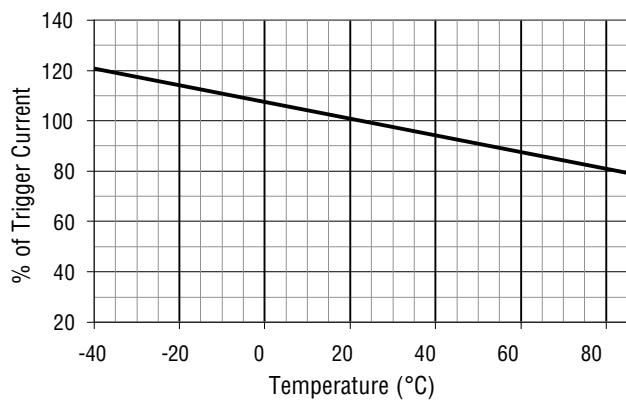
V-I Characteristics



Time to Block vs. Fault Current



Trigger Current vs. Temperature



Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

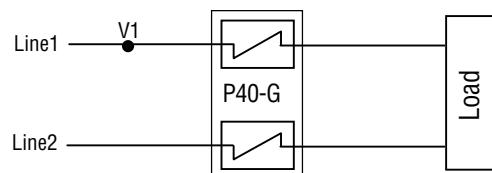
P40-G Series TBU® High-Speed Protectors

BOURNS®

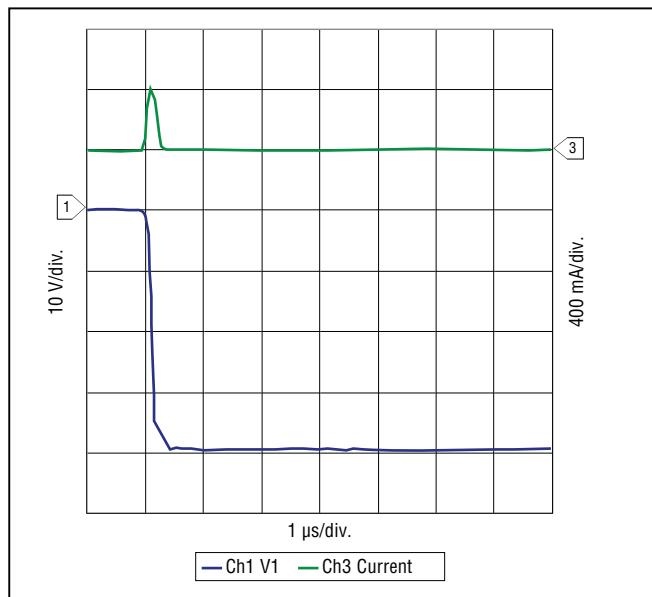
Operational Characteristics

The graph below demonstrates the operational characteristics of the TBU® device. In the graph below the fault voltage, protected side voltage, and current is presented.

TEST CONFIGURATION DIAGRAM



P40-G Lightning Protection 40 V



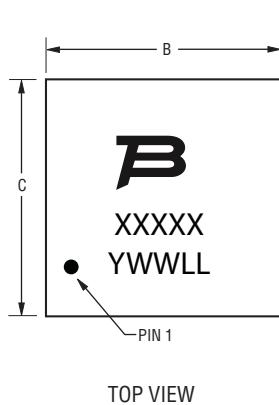
Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

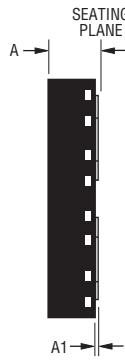
P40-G Series TBU® High-Speed Protectors

BOURNS®

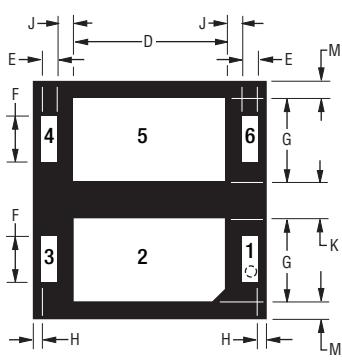
Product Dimensions



TOP VIEW



SIDE VIEW



BOTTOM VIEW

Dim.	Min.	Typ.	Max.
A	0.80 (.031)	0.90 (.035)	1.00 (.039)
A1	0.00 (.000)	0.025 (.001)	0.05 (.002)
B	3.90 (.154)	4.00 (.157)	4.10 (.161)
C	3.90 (.154)	4.00 (.157)	4.10 (.161)
D	2.55 (.100)	2.60 (.102)	2.65 (.104)
E	0.20 (.008)	0.25 (.010)	0.30 (.012)
F	0.75 (.030)	0.80 (.031)	0.85 (.033)
G	1.40 (.055)	1.45 (.057)	1.50 (.059)
H	0.10 (.004)	0.15 (.006)	0.20 (.008)
J	0.25 (.010)	0.30 (.012)	0.35 (.014)
K	0.55 (.022)	0.60 (.024)	0.65 (.026)
M	0.20 (.008)	0.25 (.010)	0.30 (.012)

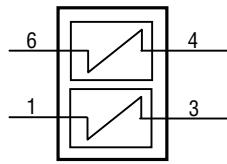
DIMENSIONS: MM
(INCHES)

Pad Designation	
Pad #	Apply
1	In1
2	NC
3	Out1
4	Out2
5	NC
6	In2

NC = Solder to PCB; do not make electrical connection, do not connect to ground.

TBU® devices have matte-tin termination finish. Suggested layout should use non-solder mask define (NSMD). Recommended stencil thickness is 0.10-0.12 mm (.004-.005 in.) with stencil opening size 0.025 mm (.0010 in.) less than the device pad size. As when heat sinking any power device, it is recommended that, wherever possible, extra PCB copper area is allowed. For minimum parasitic capacitance, do not allow any signal, ground or power signals beneath any of the pads of the device.

Block Diagram



TBU® Device

Thermal Resistances

Thermal resistance using minimal pad size, where the power is the total power dissipated in the package. Additional copper pad area to be used for additional heatsinking is also recommended.

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to Package Pads (1 TBU of Pair)	250	°C/W
R _{th(j-a)}	Junction to Package Pads (2 TBUs of Equal Power)	180	°C/W

Specifications are subject to change without notice.

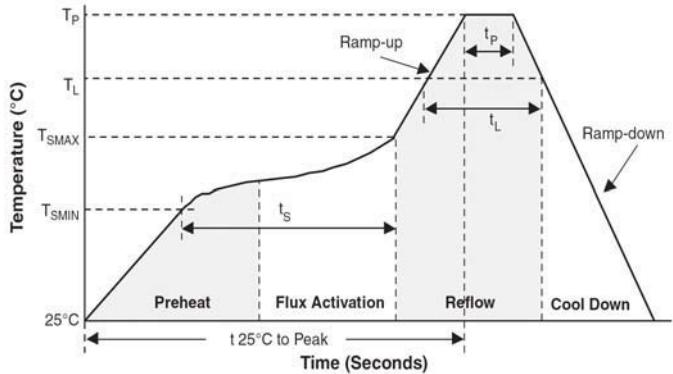
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

P40-G Series TBU® High-Speed Protectors

BOURNS®

Reflow Profile

Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (Tsmax to Tp)	3 °C/sec. max.
Preheat	
- Temperature Min. (Tsmin)	150 °C
- Temperature Max. (Tsmax)	200 °C
- Time (tsmin to tsmax)	60-180 sec.
Time maintained above:	
- Temperature (TL)	217 °C
- Time (tL)	60-150 sec.
Peak/Classification Temperature (Tp)	260 °C
Time within 5 °C of Actual Peak Temp. (tp)	20-40 sec.
Ramp-Down Rate	6 °C/sec. max.
Time 25 °C to Peak Temperature	8 min. max.



How to Order

P 40 - G 240 - WH

Form Factor _____

P = Two TBU® protectors in one device

Impulse Voltage Rating _____

40 = 40 V

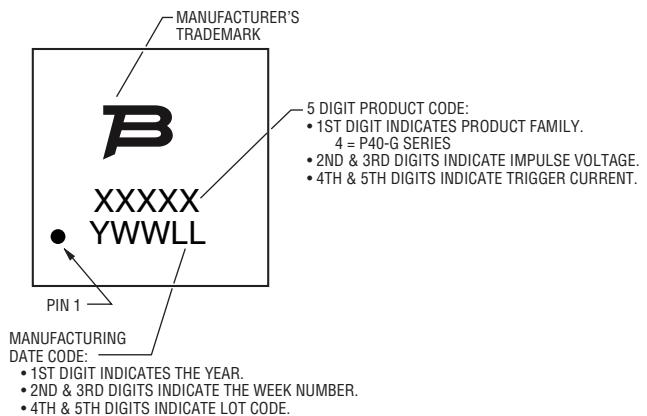
Directional Indication _____

G = Bidirectional

lop Indicator _____

240 = 240 mA

Typical Part Marking



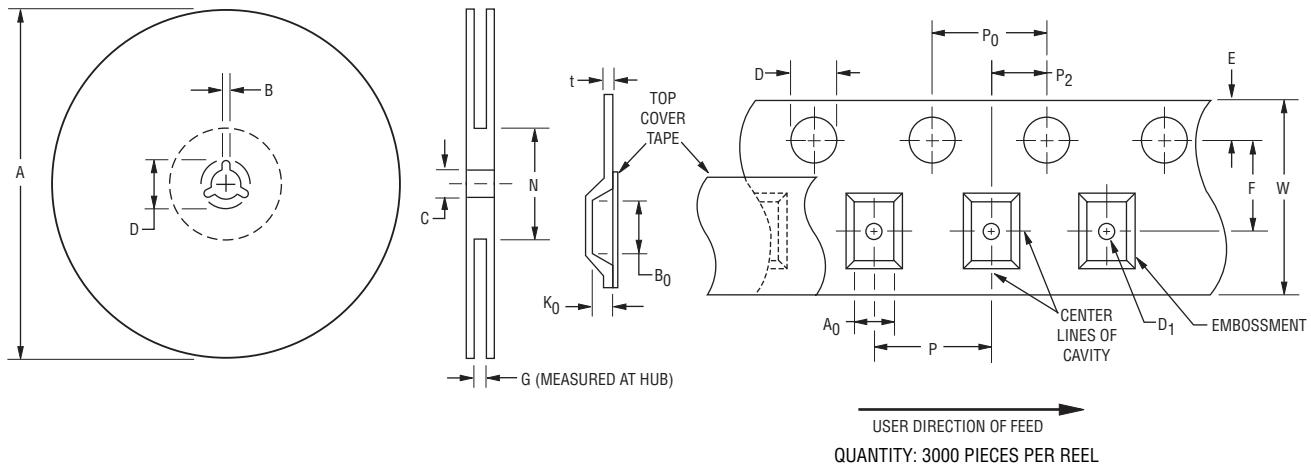
Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

P40-G Series TBU® High-Speed Protectors

BOURNS®

Packaging Specifications (per EIA468-B)



Device	A		B		C		D		G	N
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Ref.	Ref.
P40-G240	326 (12.835)	330.25 (13.002)	1.5 (.059)	2.5 (.098)	12.8 (.504)	13.5 (.531)	20.2 (.795)	-	12.4 (.488)	102 (4.016)

Device	A ₀		B ₀		D		D ₁		E		F	
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	max.
P40-G240	4.2 (.165)	4.4 (.173)	4.2 (.165)	4.4 (.173)	1.5 (.059)	1.6 (.063)	1.5 (.059)	-	1.65 (.065)	1.85 (.073)	5.45 (.216)	5.55 (.219)
Device	K ₀		P		P ₀		P ₂		t		W	
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
P40-G240	1.05 (.041)	1.25 (.049)	7.9 (.311)	8.1 (.319)	3.9 (.159)	4.1 (.161)	1.9 (.075)	2.1 (.083)	0.25 (.010)	0.35 (.014)	11.7 (.461)	12.3 (.484)

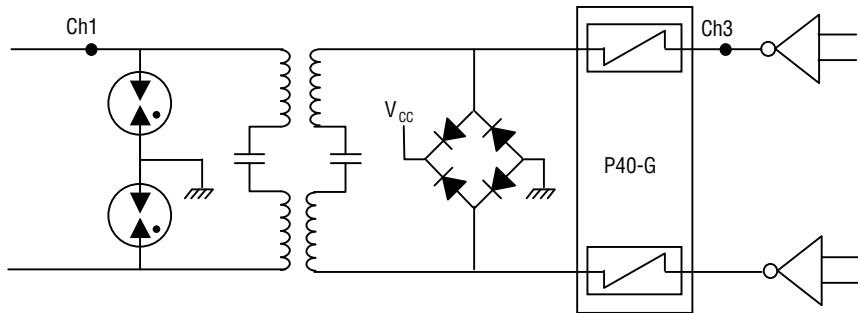
DIMENSIONS: MM
(INCHES)

P40-G Series TBU® High-Speed Protectors

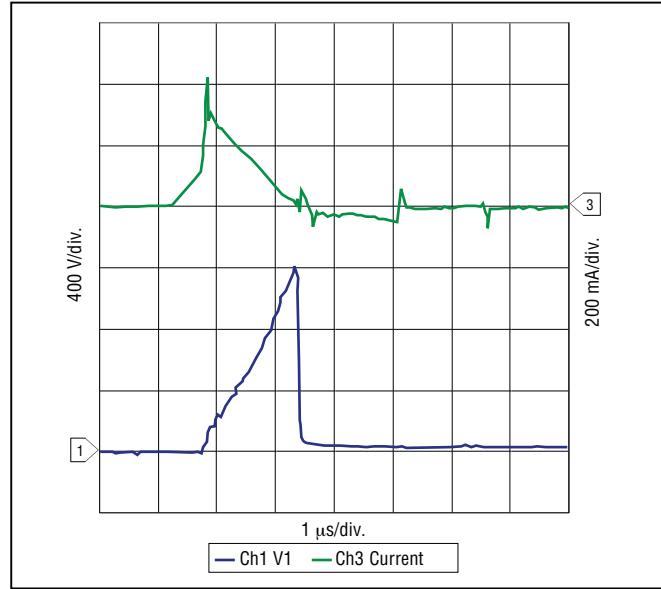
BOURNS®

Reference Application

A cost-effective protection solution combines the Bourns® TBU® protection device with a diode bridge on the driver side of the transformer and GDTs on the line side. The GDT should have a minimum DCBD of 900 V and a maximum sparkover voltage of 1600 V. The diagram below illustrates a common configuration of these components. The graph demonstrates the operational characteristics of the circuit.



Common Configuration Diagram - xDSL Protection



5000 V Lightning 2/10 μsec, 500 A

BOURNS®

Asia-Pacific: Tel: +886-2 2562-4117 • Fax: +886-2 2562-4116

EMEA: Tel: +36 88 520 390 • Fax: +36 88 520 211

The Americas: Tel: +1-951 781-5500 • Fax: +1-951 781-5700

www.bourns.com

REV. 09/15

"TBU" is a registered trademark of Bourns, Inc. in the United States and other countries.
Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
Users should verify actual device performance in their specific applications.